

EECS105 Spring 2011 Midterm 2
Open book, open notes, no silicon.

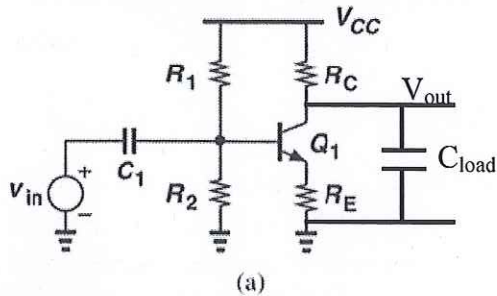
Name Key

SID _____

Wrong sign -1
 $-\frac{\pi}{4}, +\frac{\pi}{4}, \dots$ -2
 $+\frac{\pi}{4}$ if $\frac{\pi}{4}, \dots$ -4
 without derivation

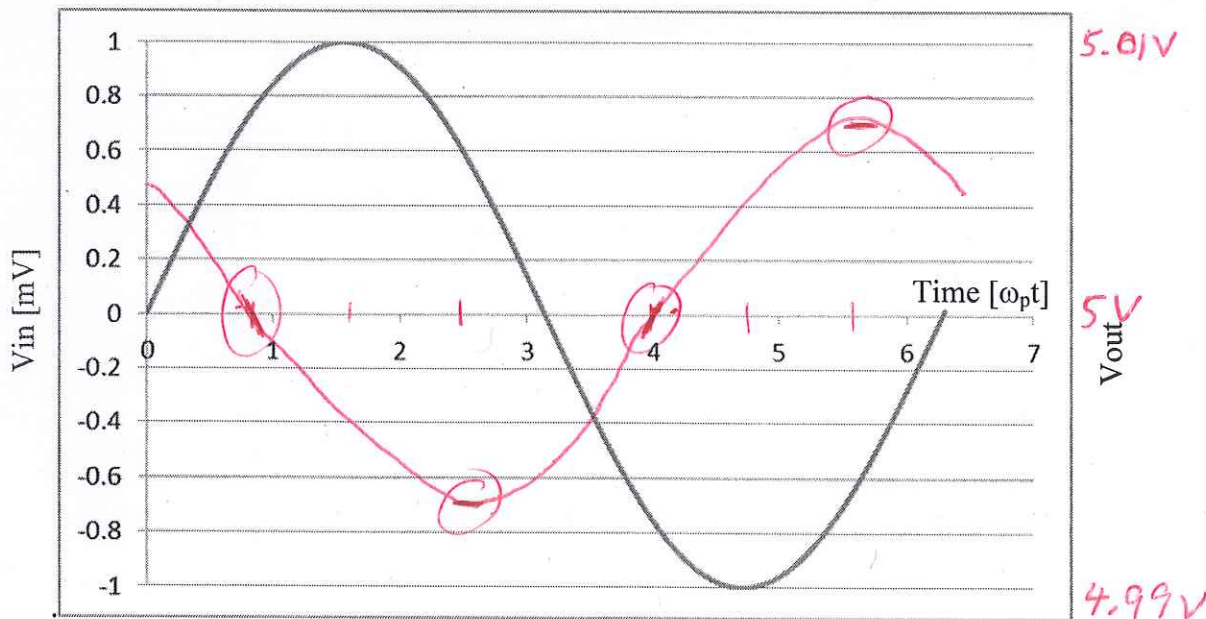
Prob.	Score
1	/20
2	/20
3	/15
4	/20
5	/25
Total	/100

1) In the circuit below with $R_E=10k$, $R_C=100k$ and $C_{load}=1pF$, calculate the frequency ω_p of the output pole, and the magnitude and phase of the transfer function from v_{in} to v_{out} at the output pole frequency, accurate to 10%. Sketch the output waveform in response to an input $V_{in}=1mV \sin(\omega_p t)$. I've drawn the input waveform and labeled the axes. Draw the output waveform and label the right axis. Assume the bias point for V_E is 0.5V, $V_{CC}=10V$, $V_A=100V$, and the input pole is at very low frequency.



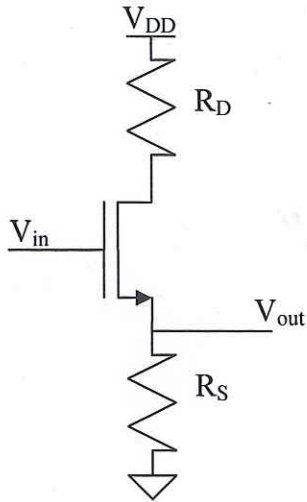
$\omega_p = 10^7 \frac{rad}{sec}$
 $|H(j\omega_p)| = 7$
 $Angle(H(j\omega_p)) = -\frac{5\pi}{4}, \frac{3\pi}{4}, -225^\circ, +135^\circ$

+10 -2
 +0.7 -2
~~Negative~~
~~positive~~ -1
 -10 -3
 -7 -1
 -0.7 -3



amplitude 2 } no labels -2 if ab "0.7"
 offset 1 } -3 otherwise
 phase 2

2) For the source follower circuit below,



2A) Draw the small signal model for this circuit.

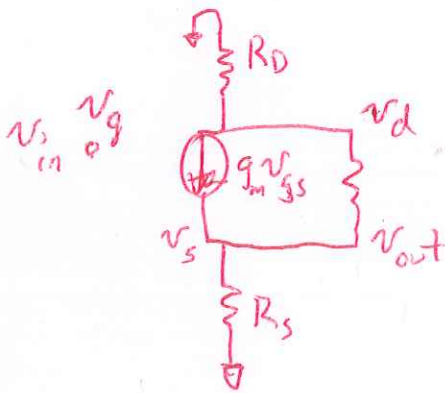
Label every node.

2B) Simplify the circuit assuming that you want to calculate G_M . **State the assumption that allows the simplification.**

2C) Write down KCL at the output node.

2D) Solve for the transconductance, G_M . (no credit on this one without showing your work).

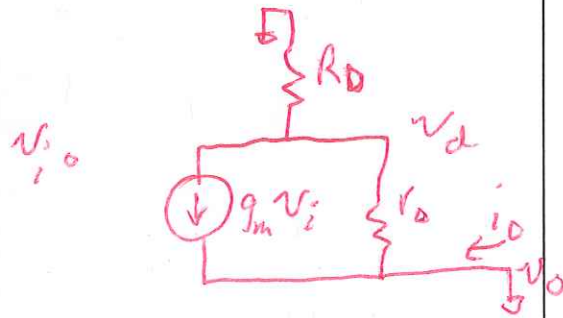
2A) Small signal model



2B) Simplified for G_M calculation

Assuming:

$$v_o = 0 \quad 1 \text{ pt}$$



2C) KCL @ v_o

$$i_o + g_m v_i + \frac{1}{r_o} v_{ds} = 0$$

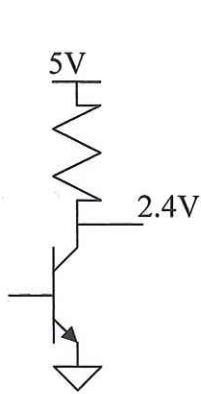
$$v_d = i_o R_D \quad i_o + \frac{1}{r_o} (i_o R_D) = -g_m v_i$$

$$\left(1 + \frac{R_D}{r_o}\right) i_o = -g_m v_i$$

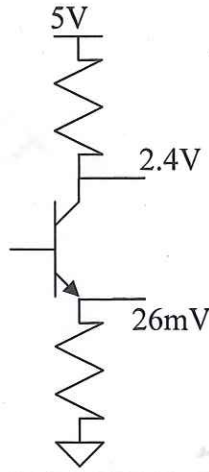
2D) $G_M =$

$$\frac{-g_m}{1 + \frac{R_D}{r_o}} = \frac{-g_m r_o}{r_o + R_D}$$

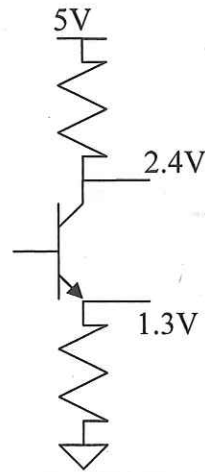
3) For the common emitter amplifiers below, given the bias points as shown, calculate the gain for each amplifier, accurate to 10%. The transistor is a 2n3904 like you've used in lab. You should be able to get a numerical answer.



$A_v = -100$



$A_v = -50$



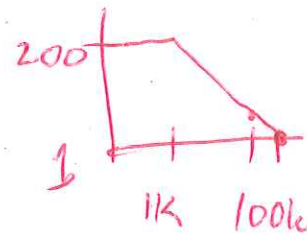
$A_v = -2$

- o no negative -1'
- o 2nd. $|A_v| = 100$ -3'
- o 5' for each.

-100 -3

4) You have a single-pole amplifier with a low frequency gain of 200, and a gain of 2 at 100kHz. What is the gain at the frequencies below?

Frequency	Gain
10 Hz	200
10kHz	20
200kHz	1
2MHz	0.1



- o minus sign -1'
- o 5' for each.

5A) For the circuit below, calculate the transconductance, output resistance. Write your answer in terms of g_{m1} , g_{m2} , r_{o1} , etc. Assume that $g_{m}r_o \gg 1$ for all combinations of g_m and r_o , and simplify your answers. Then calculate the voltage gain with the additional assumption that all transconductances are equal to g_m and all output resistances are equal to r_o , and simplify.

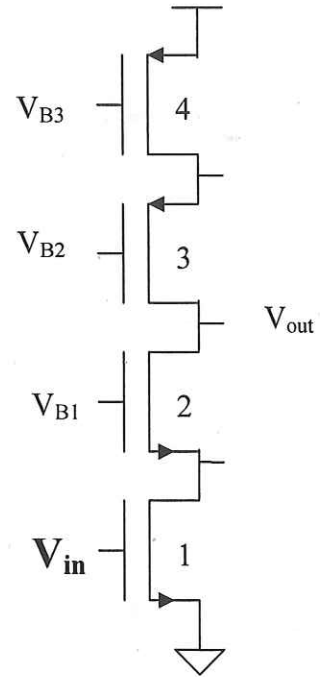
Handwritten notes and boxed answers:

4' ———

Rup-3', Rdown-3', Rtot=Rup/Rdown 2'

$G_M = g_{m1}$
$R_o = g_{m2}r_{o2}r_{o1} \parallel g_{m3}r_{o3}r_{o4}$
$A_v = -\frac{1}{2} (g_m r_o)^2$

o 4'
o No negative -1'



- 9 (3' for each)
- 5B) If you increase the boron (acceptor) doping level in the P-type substrate of an NMOS transistor, the
- Surface potential with $V_{GS}=0$ will go increase or decrease?
 - Electric field in the oxide with $V_{GS}=0$ will increase or decrease?
 - Threshold voltage will increase or decrease?